Translation

PATENT COOPERATION TREATY



PCT

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference 2001P16203WO		RTHER ACTION See Notification of Transmittal of International Preliminary Examination Report (Form PCT/IPEA/416)				
International application No. PCT/DE2003/000906	International filing date (day/montal 19 March 2003 (19.03.20					
International Patent Classification (IPC) or national classification and IPC H01L 29/24						
Applicant SICED ELECTRONICS DEVELOPMENT GMBH & CO. KG						
 This international preliminary examination report has been prepared by this International Preliminary Examining Authority and is transmitted to the applicant according to Article 36. 						
2. This REPORT consists of a total of	5 sheets, including th	is cover sheet.				
This report is also accompanied by ANNEXES, i.e., sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications made before this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions under the PCT).						
These annexes consist of a to	tal of 5 sheets.					
3. This report contains indications relating to the following items:						
I Basis of the report						
II Priority	II Priority					
III Non-establishment of	of opinion with regard to novelty, inv	ventive step and industrial applicability				
IV Lack of unity of inve	IV Lack of unity of invention					
V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement						
VI Certain documents cited						
VII Certain defects in th	VII Certain defects in the international application					
VIII Certain observations on the international application						
Date of submission of the demand	Date of con	apletion of this report				
14 October 2004 (14.10	.2004)	26 July 2005 (26.07.2005)				
Name and mailing address of the IPEA/EP	Authorized	Authorized officer				
Facsimile No.	Telephone	Telephone No.				



International application No.

PCT/DE2003/000906

1-	I. Basis of the report								
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		pages							, filed with the deman
		pages			4, 4a		, filed with	the letter of	23 March 2005 (23.03.2005)
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		pages					, as am	ended (together	r with any statement under Article 1
		pages							. filed with the deman
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3.	With		to any nucl xamination wanted and in the inter	as carried of	ut on the bas	212 OT THE SEC	quence listing:	in the internat	ional application, the internationa
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4.		1 1	nendments hav						
			the description						
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			the drawings,			· <u> </u>			
5.		This rep beyond t	ort has been of the disclosure	established as as filed, as	as if (some of indicated in	of) the ame	endments had not mental Box (Rule	been made, sin 70.2(c)).**	nce they have been considered to go
*.	Repla in thi and 7	icement s. is report 10.17).	heets which h as "original	ıave been fu lly filed" a	rnished to ti nd are not	he receiving annexed to	3 Office in respon 5 this report sinc	se to an invitat ce they do not	tion under Article 14 are referred to t contain amendments (Rule 70.16
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V .	Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1.	Statement			
	Novelty (N)	Claims	1-17	YES
		Claims		NO
	Inventive step (IS)	Claims	1-17	YES
		Claims		NO
İ	Industrial applicability (IA)	Claims	1-17	YES
		Claims		NO NO

2. Citations and explanations

1. This report makes reference to the following document:

D1: DE-A-19900169

- 2. The newly submitted claim 1 results from a combination of the features of the originally submitted claims 1 and 6 and is therefore admissible (PCT Articles 19(2) and 34(2)(b)).
- 3. The newly submitted claim 1 is construed in light of the description and of the embodiments explained therein.

In particular, the part of the first semiconductor region located above the buried islet region and within which current can be influenced by means of a depletion zone is identified as being the channel region.

Moreover, the wording "the channel regions include a channel conduction region for conducting the current..." is interpreted restrictively (according to the meaning indicated in the description). Since the

channel conduction region is delimited above and below in all the embodiments from the part of the channel region having only the basic doping, the word "include" (in German "umfasst") is construed to mean "enclose", not only "has".

If the newly submitted claim 1 is understood as explained above, the subject matter of this claim is novel over the prior art. The newly submitted claim 1 differs from the closest prior art, document D1, in that a so-called highly doped channel conduction region is located inside the channel region (rather than constituting the entire channel region). This channel conduction region is "embedded" in the part of the channel region with the base doping, i.e. it is delimited above and below from the latter. For this reason, in conducting operation, the current flows preferably in the channel conduction region and the remaining channel region remains currentfree. Parameter setting fluctuations for the channel region thus play a very small role in the operation of the component as per claim 1 of the present application. On the contrary, the thickness and doping substance concentration settings of the channel conduction region can be more easily controlled technologically. This represents an improvement over the component disclosed in D1, with respect to technological stability, i.e. greater independence from technologically created fluctuations, possibly leading to a higher yield of the manufacturing process. In addition, the temperature-dependence of the component currentswitching capability is reduced. Consequently, the subject matter of the newly submitted claim 1 of the present application appears to be inventive.

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Claims 2-17 are dependent on claim 1 and therefore likewise meet the PCT novelty and inventive step requirements.